

Features

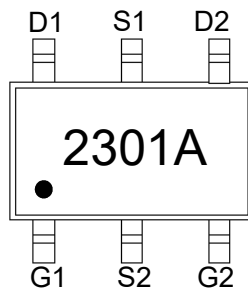
- Leading trench technology for low $R_{DS(on)}$
- Low Gate Charge

Product Summary

V_{DS}	$R_{DS(on)}$ MAX	I_D MAX
-20V	65mΩ@-4.5V	-3.7A
	90mΩ@-2.5V	

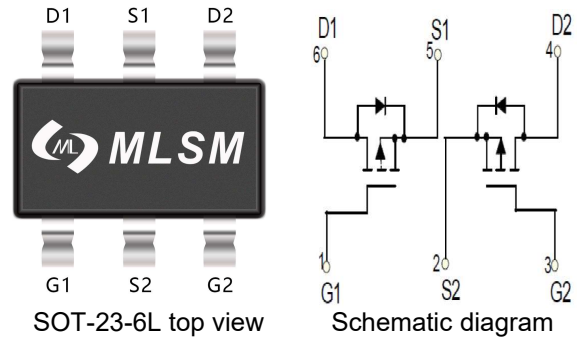
Application

- Video monitor
- Power management



2301A: Device code

Marking and pin assignment



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V _{DS}	Drain-Source Breakdown Voltage		-20	V
V _{GS}	Gate-Source Voltage		±10	V
T _J	Maximum Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-55 to 150	°C
I _S	Diode Continuous Forward Current	Tc=25°C	-3.7	A

Mounted on Large Heat Sink

I_{DM}	Pulse Drain Current Tested	$T_c=25^\circ\text{C}$	-16	A
I_D	Continuous Drain Current	$T_c=25^\circ\text{C}$	-3.7	A
P_D	Maximum Power Dissipation	$T_c=25^\circ\text{C}$	1.3	W
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient		96	°C/W

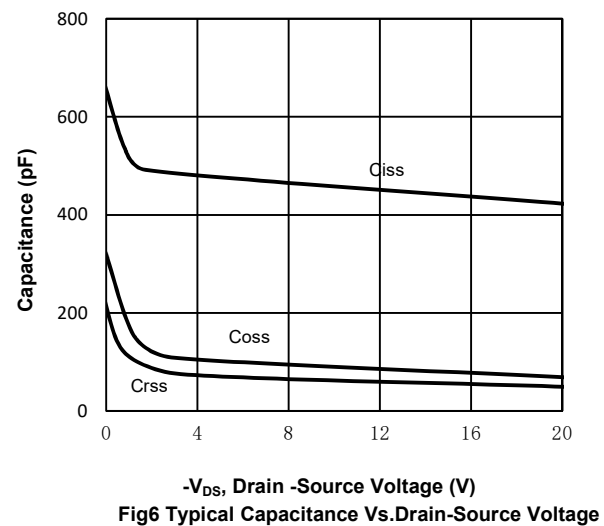
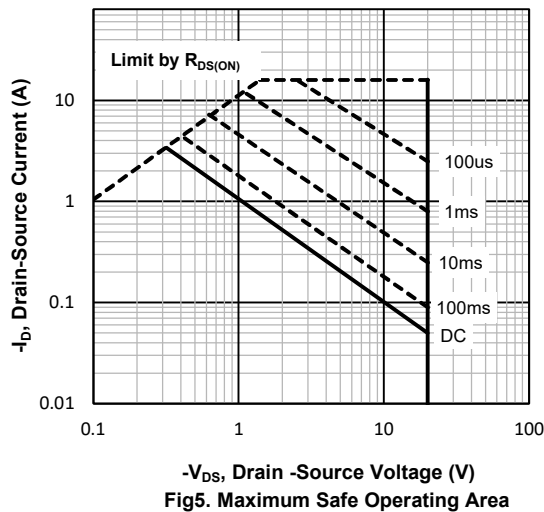
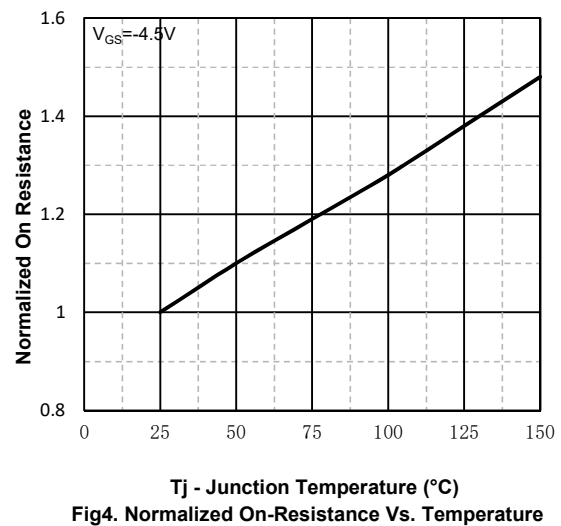
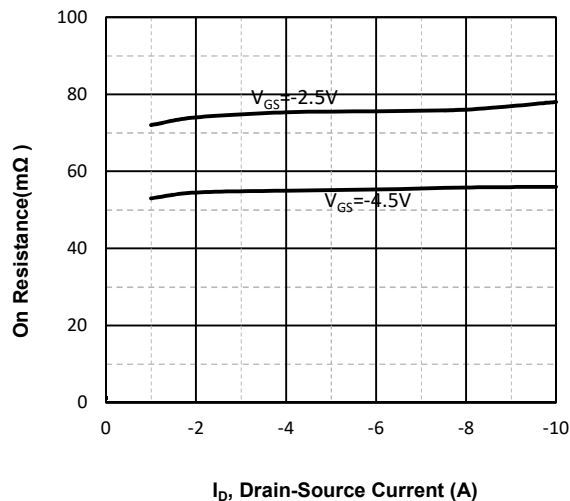
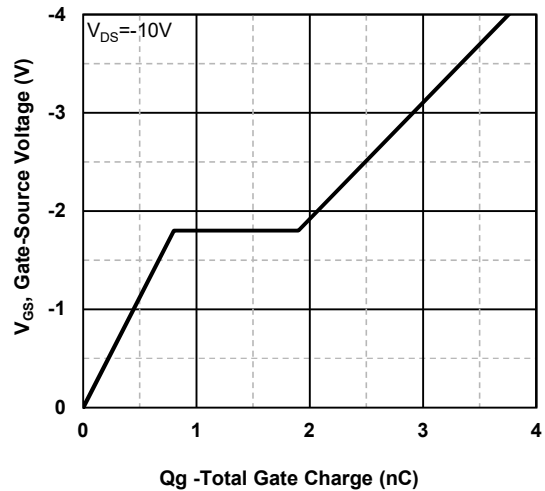
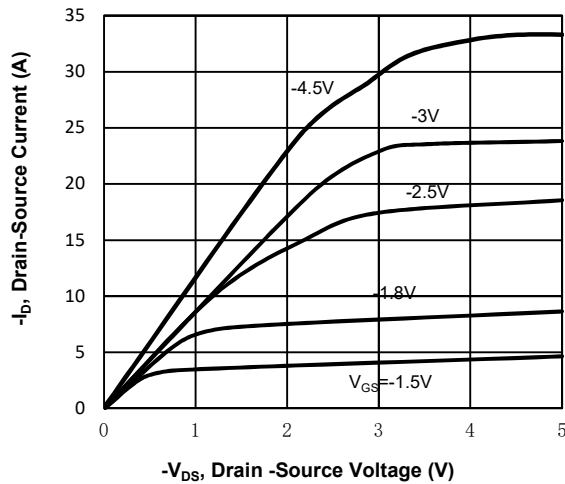
Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLSL2301A	SOT-23-6L	2301A	3,000	45,000	180,000	7"reel

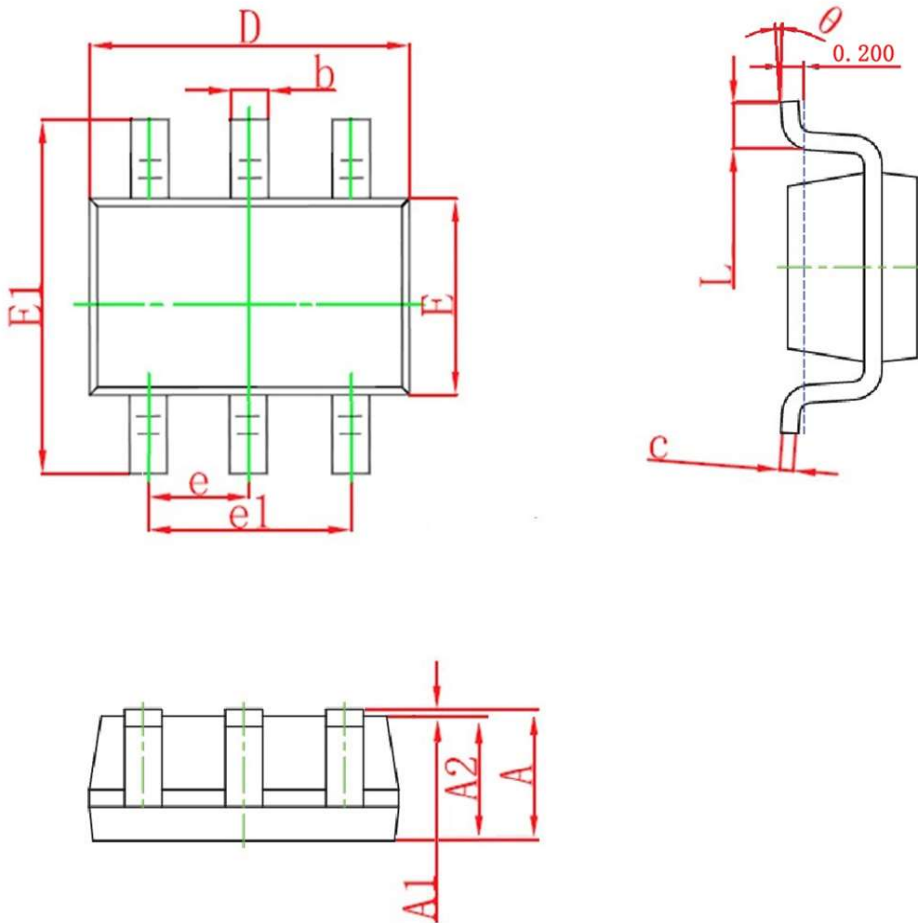
Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
BV(BR)DSS	Drain-Source Breakdown Voltage	VGS=0V, ID=-250μA	-20	–	–	V
IDSS	Zero Gate Voltage Drain Current	VDS=-20V, VGS=0V	--	–	-1	μA
IGSS	Gate-Body Leakage Current	VGS=±10V, VDS=0V	--	–	±100	nA
VGS(th)	Gate Threshold Voltage	VDS=VGS, ID=-250μA	-0.4	-0.62	-1.0	V
RDS(on)	Drain-Source On-State Resistance	VGS=-4.5V, ID=-3.7A	--	55	65	mΩ
		VGS=-2.5V, ID=-3.0A	--	73	90	mΩ
		VGS=-1.8V, ID=-2.5A	--	100	180	mΩ
Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
CISS	Input Capacitance	VDS=-10V, VGS=0V, f=1MHz	–	438	–	pF
COSS	Output Capacitance		–	76	–	pF
CRSS	Reverse Transfer Capacitance		–	62	–	pF
Switching Characteristics						
Qg	Total Gate Charge	VDS=-10V, ID=-3.7A, VGS=-4.5V	–	5.41	–	nC
Qgs	Gate Source Charge		–	1.17	–	nC
Qgd	Gate Drain Charge		–	1.24	–	nC
td(on)	Turn-on Delay Time	VDD=-10V, ID=-1A, VGS=-4.5V, RG=3Ω	--	6.4	–	nS
tr	Turn-on Rise Time		–	21.8	–	nS
td(off)	Turn-Off Delay Time		–	37.4	–	nS
tf	Turn-Off Fall Time		–	34	–	nS
Source- Drain Diode Characteristics						
VSD	Forward on voltage	TJ=25°C, Is=-3.7A	–	–	-1.2	V

Typical Operating Characteristics



SOT-23-6L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.000	1.200	0.039	0.047
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.600	3.000	0.102	0.118
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
K	0°	8°	0°	8°